Voltage comparator NE529

DESCRIPTION

The NE529 is a high-speed analog voltage comparator which, for the first time, mates state-of-the-art Schottky diode technology with the conventional linear process. This allows simultaneous fabrication of high-speed TTL gates with a precision linear amplifier on a single monolithic chip.

FEATURES

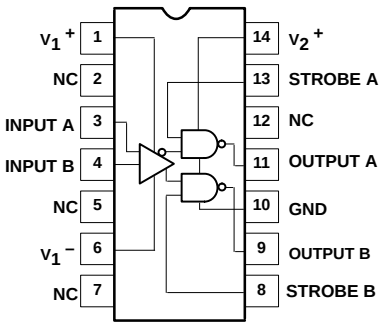
- 10ns propagation delay
- Complementary output gates
- TTL or ECL compatible outputs
- Wide common-mode and differential voltage range
- Typical gain 5000

APPLICATIONS

- A/D conversion
- ECL-to-TTL interface
- TTL-to-ECL interface
- Memory sensing
- Optical data coupling

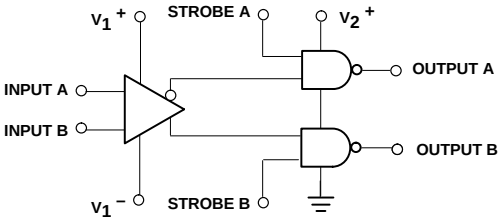
PIN CONFIGURATIONS

D, N Packages



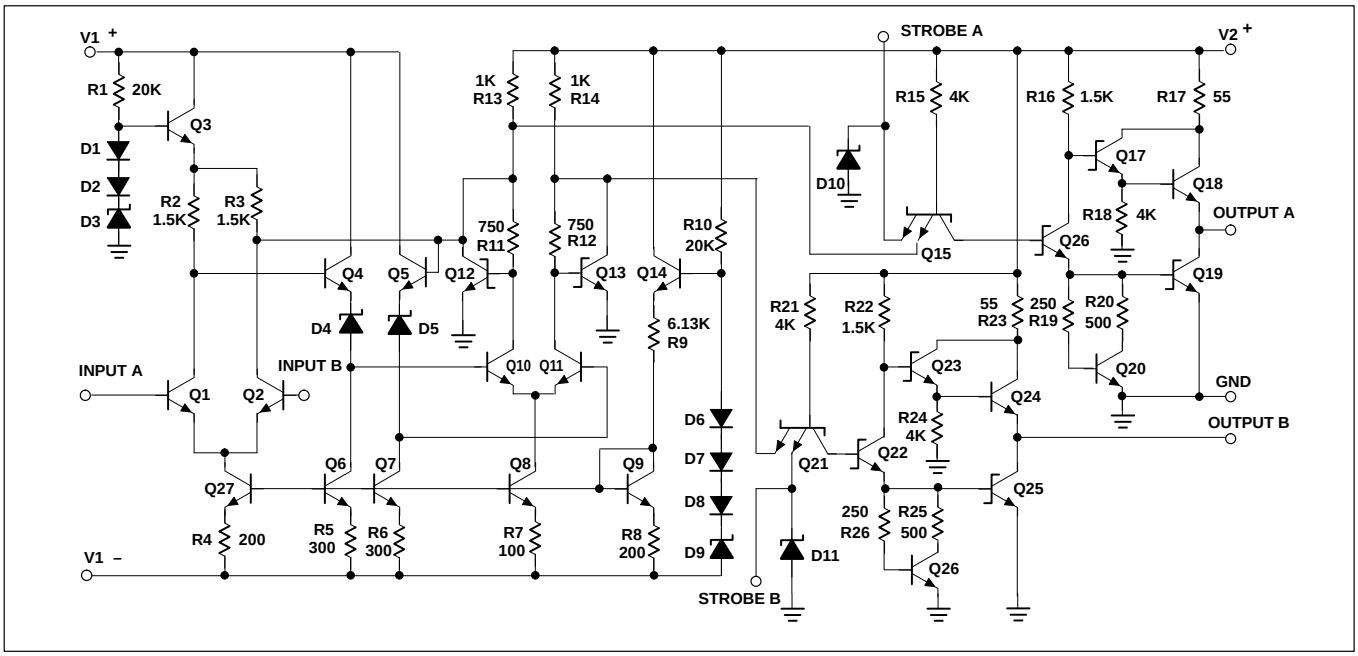
TOP VIEW

BLOCK DIAGRAM



ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Dual In-Line Package (DIP)	0 to +70°C	NE529N	0405B
14-Pin Small Outline (SO) Package	0 to +70°C	NE529D	0175D



ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_1+	Positive supply voltage	+15	V
V_1-	Negative supply voltage	-15	V
V_2+	Gate supply voltage	+7	V
V_{OUT}	Output voltage	+7	V
V_{IN}	Differential input voltage	±5	V
V_{CM}	Input common mode voltage	±6	V
P_D	Maximum power dissipation[1] T_A=25°C (still-air)		
	N package	1420	mW
	D package	1040	mW
T_A	Operating temperature range	0 to +70	°C
T_{STG}	Storage temperature range	-65 to +150	°C
T_{SOLD}	Lead soldering temperature		
	(10 sec max)	+300	°C

NOTES:
1. Derate above 25°C at the following rates:
   N package at 11.5mW/°C
   D package at 8.3mW/°C

DC ELECTRICAL CHARACTERISTICS

V_1+=+10V, V_2+=+5.0V, V_1-=-10V, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	NE529			UNIT
			Min	Typ	Max	
Input characteristics						
V_{OS}	Input offset voltage @ 25°C				6	mV
	Over temperature range				10	
I_{BIAS}	Input bias current @ 25°C			5	20	µA
	Over temperature range	V_{IN}=0V			50	
I_{OS}	Input offset current @ 25°C			2	5	µA
	Over temperature range	V_{IN}=0V			15	µA
V_{CM}	Common-mode voltage range		-5	0		V
Gate characteristics						
V_{OUT}	Output voltage					
	"1" state	V_2+=4.75V, I_{SOURCE}=-1mA	2.7	3.3		V
	"0" state	V_2+=4.75V, I_{SINK}=10mA			0.5	V
	Strobe inputs					
	"0" Input current[1]	V_2+=5.25V, V_{STROBE}=0.5V			-2	mA
	"1" Input current @ 25°C[1]	V_2+=5.25V, V_{STROBE}=2.7V			100	µA
	Over temperature range	V_2+=5.25V, V_{STROBE}=2.7V			200	µA
	"0" input voltage	V_2+=4.75V			0.8	V
	"1" input voltage	V_2+=4.75V	2.0			V
I_{SC}	Short-circuit output current	V_2+=5.25V, V_{OUT}=0V	-18		-70	mA
Power supply requirements						
	Supply voltage					
V_1+			5		10	V
V_1-			-6		-10	V
V_2+			4.75	5	5.25	V
	Supply current	V_1+=10V, V_1-=-10V				
		V_2+=5.25V				
I_1+		Over temp.			5	mA
I_1-		Over temp.			10	mA
I_2+		Over temp.			20	mA

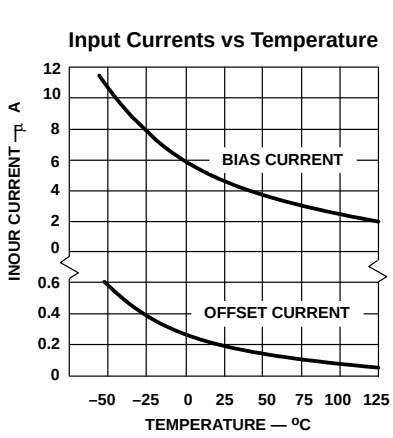
NOTES:
1. See logic function table.

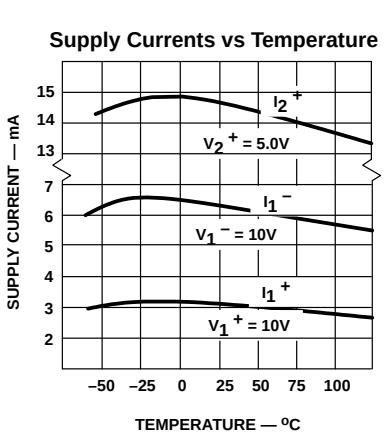
AC ELECTRICAL CHARACTERISTICS

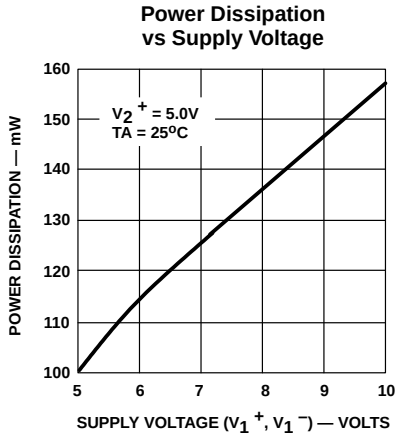
T_A=25°C (See AC test circuit).

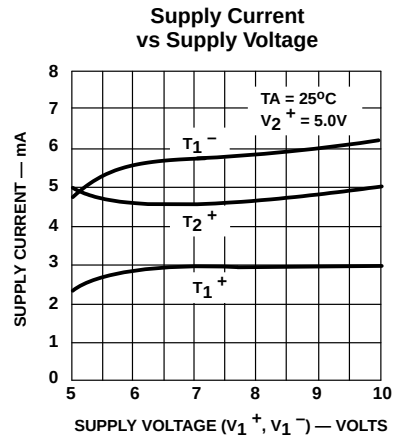
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Min	Typ	Max	
t_R	Transient response	V_{IN}=±100mV step				
	Propagation delay time					
t_{PLH}	Low-to-high			12	22	ns
t_{PHL}	High-to-low			10	20	ns
	Delay between output A and B			2	5	ns
	Strobe delay time					
t_{ON}	turn-on time			6		ns
t_{OFF}	turn-off time			6		ns

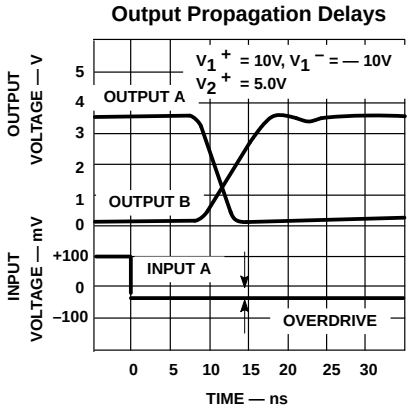
TYPICAL PERFORMANCE CHARACTERISTICS

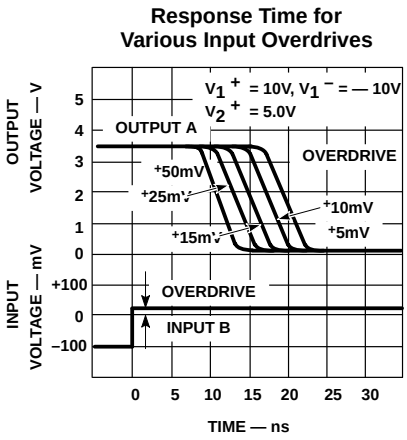




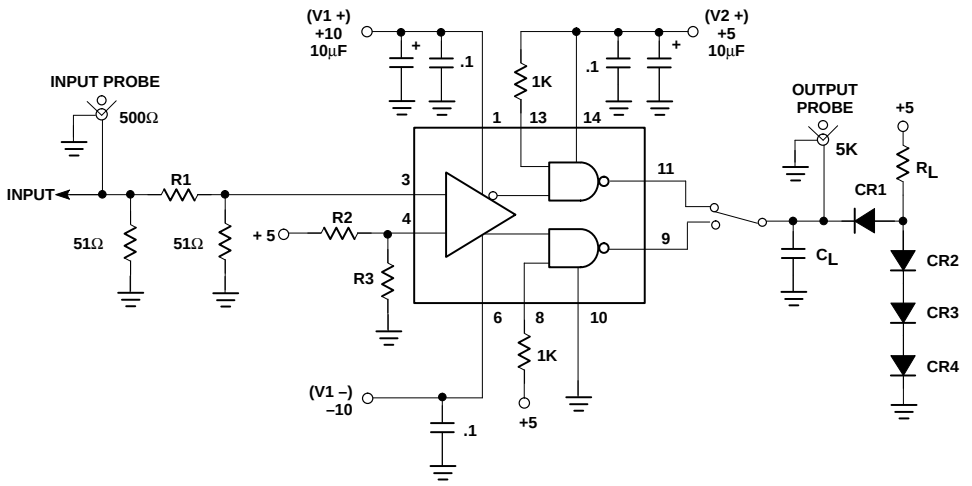








RESPONSE TIME TEST CIRCUIT



NOTES:
CR1 — CR4 = IN914
R1 selected for 15.1 divider
R2, 3 selected for 100mV at Pin 4

Input
PRR = 1MHz
P_W = 50ns
$T_r = T_f$ = 2ns
Amplitude = 3.00V

Output
R_L = 390Ω
C_L = 25pF (including stray capacitance

APPLICATIONS

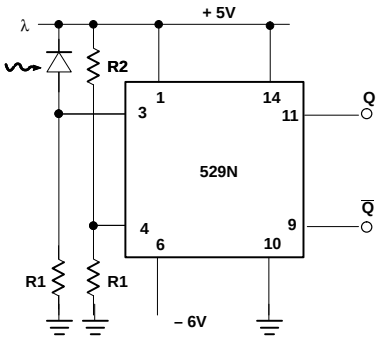
One of the main features of the device is that supply voltages (V+, V-) need not be balanced, as in the following diagrams. For proper operation, however, negative supply (V-) should always be at least 6V more than the ground terminal (pin 6). Input Common-Mode range should be limited to values of 2V less than the supply voltages (V+ and V-) up to a maximum of ±5V as supply voltages are increased.

It is also important to note that Output A is in phase with Input A and Output B is in phase with Input B.

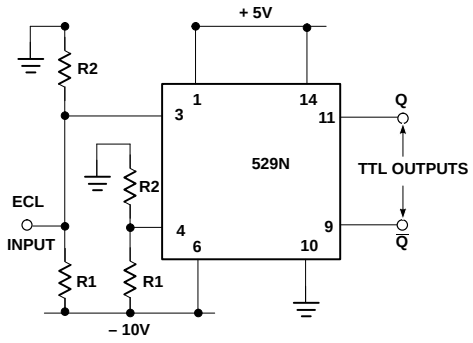
LOGIC FUNCTION

V_{ID} (A^+, B^-)	STROBE A	STROBE B	OUTPUT A	OUTPUT B
$V_{ID} \leq -V_{OS}$	H	X	L	H
$-V_{OS} < V_{ID} < V_{OS}$	H	H	Undefined	Undefined
$V_{ID} \geq V_{OS}$	X	H	H	L
X	L	L	H	H

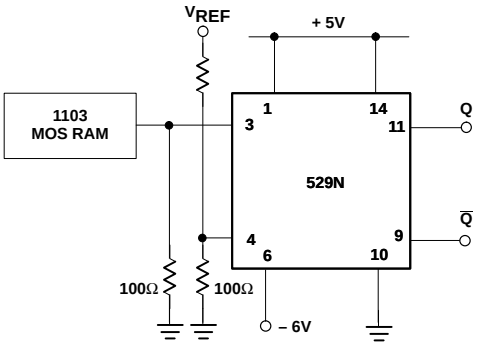
TYPICAL APPLICATIONS



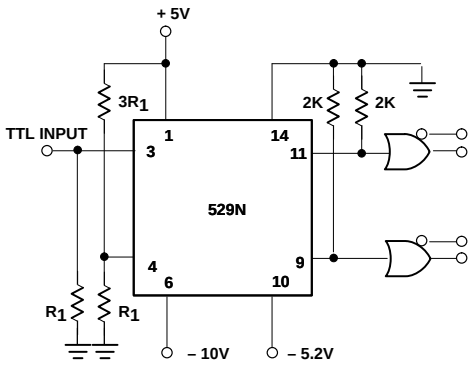
Photodiode Detector



ECL-to-TTL Interface



MOS Memory Sense AMP



TTL-to-ECL Interface